

To our customers,

Old Company Name in Catalogs and Other Documents

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Renesas Electronics website: <http://www.renesas.com>

April 1st, 2010
Renesas Electronics Corporation

Issued by: Renesas Electronics Corporation (<http://www.renesas.com>)

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MOS FIELD EFFECT TRANSISTOR

μPA2790GR

SWITCHING N- AND P-CHANNEL POWER MOS FET

DESCRIPTION

The μPA2790GR is N- and P-channel MOS Field Effect Transistors designed for Motor Drive application.

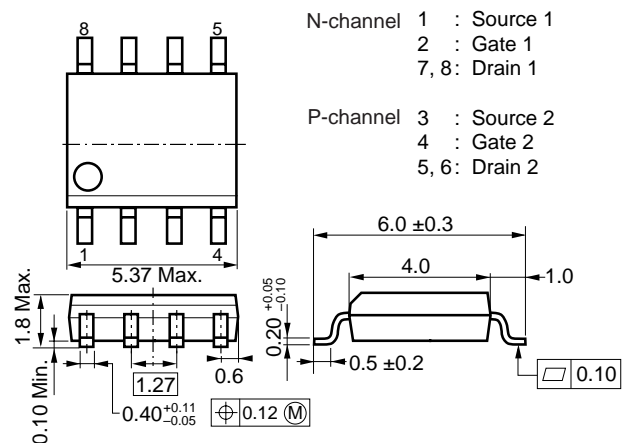
FEATURES

- Low on-state resistance
 - N-channel $R_{DS(on)1} = 28 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 10 \text{ V}$, $I_D = 3 \text{ A}$)
 - $R_{DS(on)2} = 40 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = 4.5 \text{ V}$, $I_D = 3 \text{ A}$)
 - P-channel $R_{DS(on)1} = 60 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = -10 \text{ V}$, $I_D = -3 \text{ A}$)
 - $R_{DS(on)2} = 80 \text{ m}\Omega \text{ MAX.}$ ($V_{GS} = -4.5 \text{ V}$, $I_D = -3 \text{ A}$)
- Low input capacitance
 - N-channel $C_{iss} = 500 \text{ pF TYP.}$
 - P-channel $C_{iss} = 460 \text{ pF TYP.}$
- Built-in gate protection diode
- Small and surface mount package (Power SOP8)

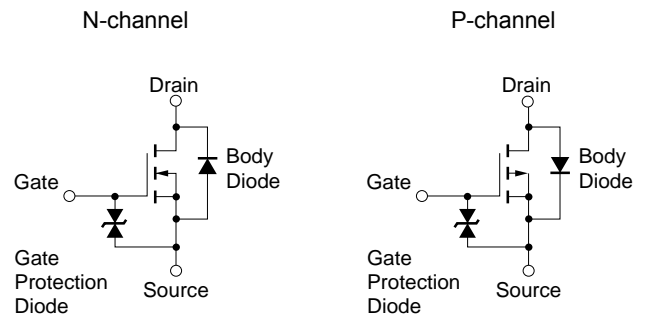
ORDERING INFORMATION

PART NUMBER	PACKAGE
μPA2790GR	Power SOP8

PACKAGE DRAWING (Unit: mm)



EQUIVALENT CIRCUITS



Remark The diode connected between the gate and source of the transistor serves as a protector against ESD.

When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

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ABSOLUTE MAXIMUM RATINGS (T_A = 25°C. All terminals are connected.)

PARAMETER	SYMBOL	N-CHANNEL	P-CHANNEL	UNIT
Drain to Source Voltage (V _{GS} = 0 V)	V _{DSS}	30	-30	V
Gate to Source Voltage (V _{DS} = 0 V)	V _{GSS}	±20	∓20	V
Drain Current (DC)	I _{D(DC)}	±6	∓6	A
Drain Current (pulse) ^{Note1}	I _{D(pulse)}	±24	∓24	A
Total Power Dissipation (1 unit) ^{Note2}	P _T	1.7		W
Total Power Dissipation (2 units) ^{Note2}	P _T	2.0		W
Channel Temperature	T _{ch}	150		°C
Storage Temperature	T _{stg}	-55 to +150		°C
Single Avalanche Current ^{Note3}	I _{AS}	6	-6	A
Single Avalanche Energy ^{Note3}	E _{AS}	3.6	3.6	mJ

Notes 1. PW ≤ 10 μs, Duty Cycle ≤ 1%

2. Mounted on ceramic substrate of 2000 mm² x 1.6 mm

3. Starting T_{ch} = 25°C, V_{DD} = $\frac{1}{2}$ x V_{DSS}, R_G = 25 Ω, L = 100 μH, V_{GS} = V_{GSS} → 0 V

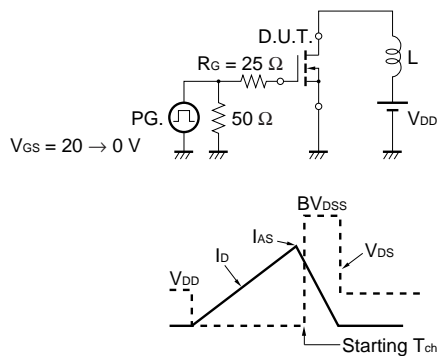
ELECTRICAL CHARACTERISTICS (T_A = 25°C. All terminals are connected.)

N-channel

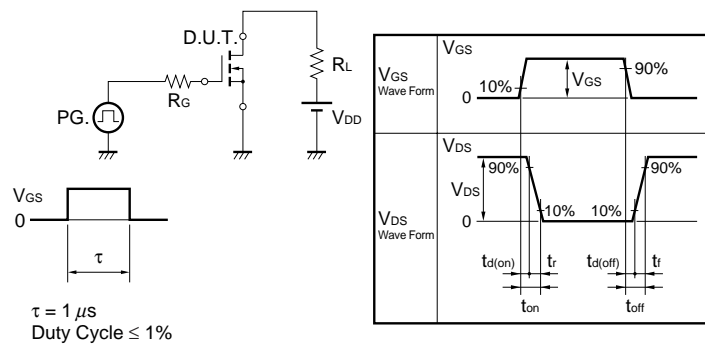
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} = 30 V, V _{GS} = 0 V			10	μA
Gate Leakage Current	I _{GSS}	V _{GS} = ±16 V, V _{DS} = 0 V			±10	μA
Gate Cut-off Voltage	V _{GS(off)}	V _{DS} = 10 V, I _D = 1 mA	1.5		2.5	V
Forward Transfer Admittance ^{Note}	y _{fs}	V _{DS} = 10 V, I _D = 3 A	2			S
Drain to Source On-state Resistance ^{Note}	R _{DS(on)1}	V _{GS} = 10 V, I _D = 3 A		21	28	mΩ
	R _{DS(on)2}	V _{GS} = 4.5 V, I _D = 3 A		28	40	mΩ
	R _{DS(on)3}	V _{GS} = 4.0 V, I _D = 3 A		34	53	mΩ
Input Capacitance	C _{iss}	V _{DS} = 10 V		500		pF
Output Capacitance	C _{oss}	V _{GS} = 0 V		135		pF
Reverse Transfer Capacitance	C _{rss}	f = 1 MHz		77		pF
Turn-on Delay Time	t _{d(on)}	V _{DD} = 15 V, I _D = 3 A		9.2		ns
Rise Time	t _r	V _{GS} = 10 V		8.8		ns
Turn-off Delay Time	t _{d(off)}	R _G = 10 Ω		28		ns
Fall Time	t _f			7.4		ns
Total Gate Charge	Q _G	I _D = 6 A		12.6		nC
Gate to Source Charge	Q _{GS}	V _{DD} = 24 V		1.7		nC
Gate to Drain Charge	Q _{GD}	V _{GS} = 10 V		3.8		nC
Body Diode Forward Voltage ^{Note}	V _{F(S-D)}	I _F = 6 A, V _{GS} = 0 V		0.85		V
Reverse Recovery Time	t _{rr}	I _F = 6 A, V _{GS} = 0 V		18		ns
Reverse Recovery Charge	Q _{rr}	di/dt = 100 A/μs		11		nC

Note Pulsed

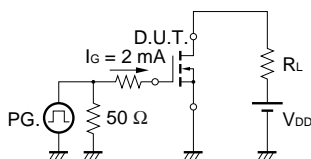
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME



TEST CIRCUIT 3 GATE CHARGE

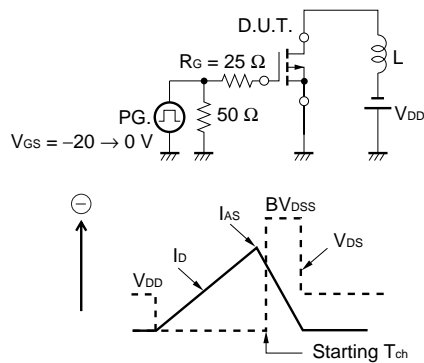


P-channel

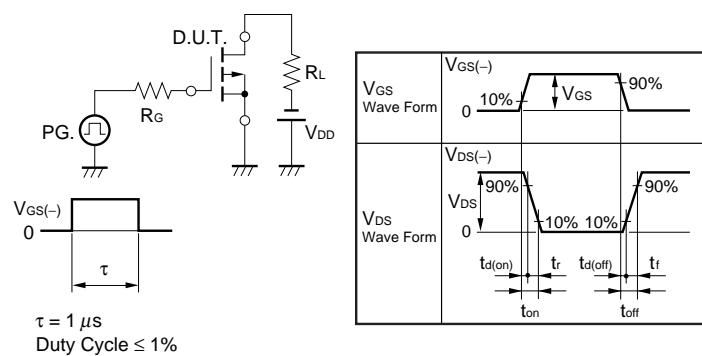
CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	I_{DSS}	$V_{DS} = -30\text{ V}, V_{GS} = 0\text{ V}$			-10	μA
Gate Leakage Current	I_{GSS}	$V_{GS} = \mp 16\text{ V}, V_{DS} = 0\text{ V}$			±10	μA
Gate Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = -10\text{ V}, I_D = -1\text{ mA}$	-1.0		-2.5	V
Forward Transfer Admittance ^{Note}	$ y_{fs} $	$V_{DS} = -10\text{ V}, I_D = -3\text{ A}$	2			S
Drain to Source On-state Resistance ^{Note}	$R_{DS(on)1}$	$V_{GS} = -10\text{ V}, I_D = -3\text{ A}$		43	60	mΩ
	$R_{DS(on)2}$	$V_{GS} = -4.5\text{ V}, I_D = -3\text{ A}$		58	80	mΩ
	$R_{DS(on)3}$	$V_{GS} = -4.0\text{ V}, I_D = -3\text{ A}$		65	110	mΩ
Input Capacitance	C_{iss}	$V_{DS} = -10\text{ V}$		460		pF
Output Capacitance	C_{oss}	$V_{GS} = 0\text{ V}$		130		pF
Reverse Transfer Capacitance	C_{rss}	$f = 1\text{ MHz}$		77		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = -15\text{ V}, I_D = -3\text{ A}$		8.5		ns
Rise Time	t_r	$V_{GS} = -10\text{ V}$		4.8		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		42		ns
Fall Time	t_f			19		ns
Total Gate Charge	Q_G	$I_D = -6\text{ A}$		11		nC
Gate to Source Charge	Q_{GS}	$V_{DD} = -24\text{ V}$		1.7		nC
Gate to Drain Charge	Q_{GD}	$V_{GS} = -10\text{ V}$		3.3		nC
Body Diode Forward Voltage ^{Note}	$V_{F(S-D)}$	$I_F = 6\text{ A}, V_{GS} = 0\text{ V}$		0.92		V
Reverse Recovery Time	t_{rr}	$I_F = 6\text{ A}, V_{GS} = 0\text{ V}$		21		ns
Reverse Recovery Charge	Q_{rr}	$di/dt = 100\text{ A}/\mu\text{s}$		12		nC

Note Pulsed

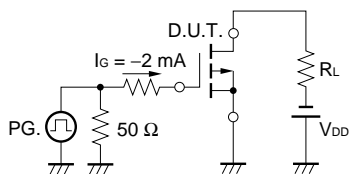
TEST CIRCUIT 1 AVALANCHE CAPABILITY



TEST CIRCUIT 2 SWITCHING TIME

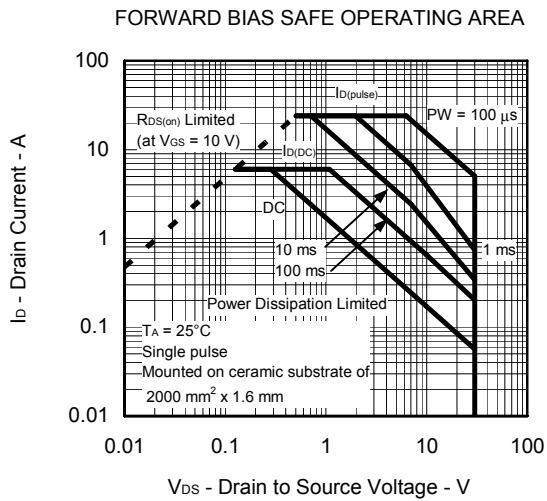
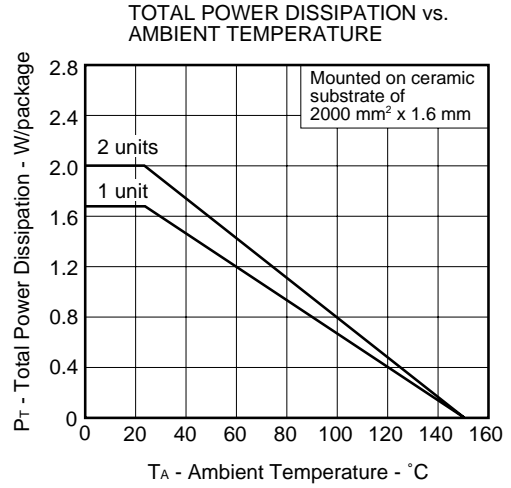
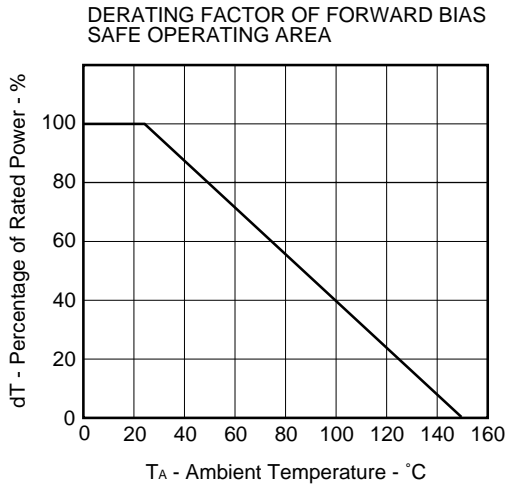


TEST CIRCUIT 3 GATE CHARGE

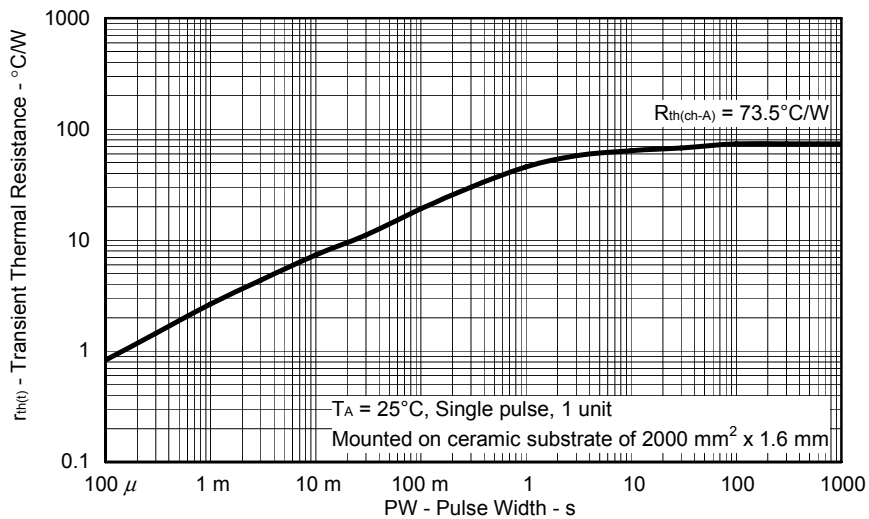


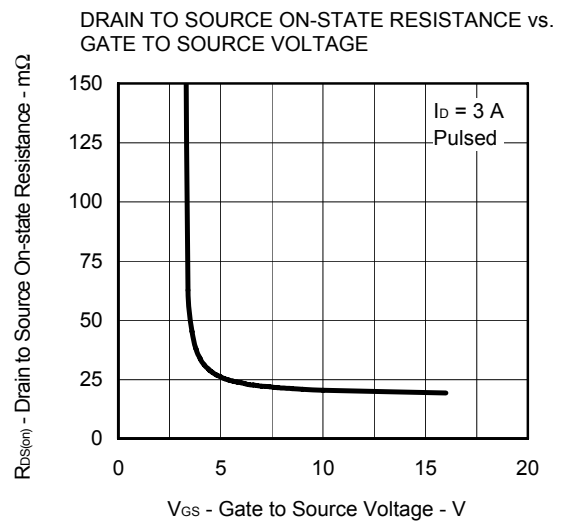
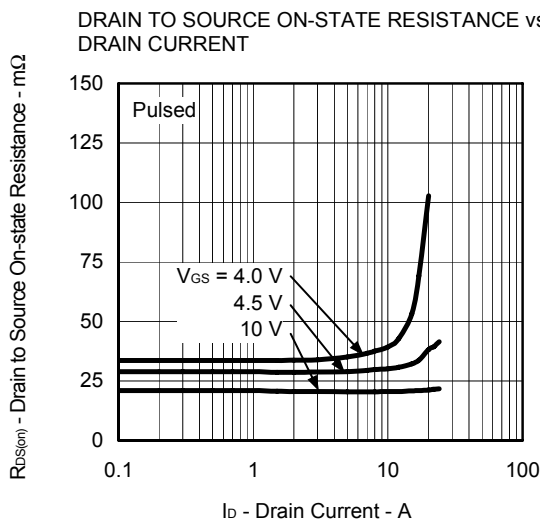
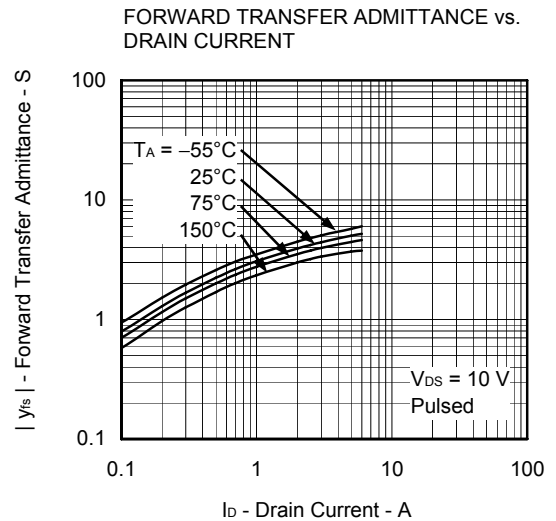
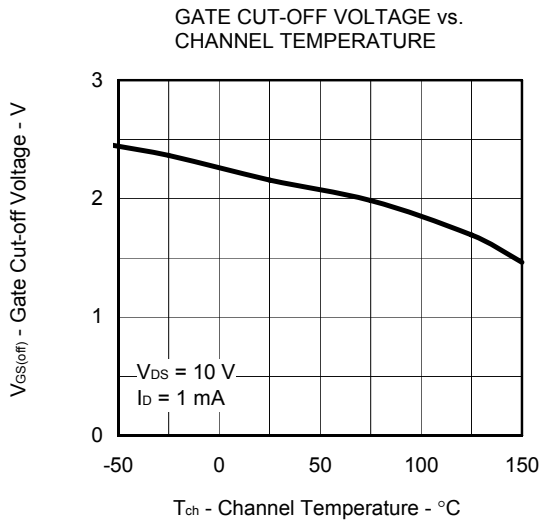
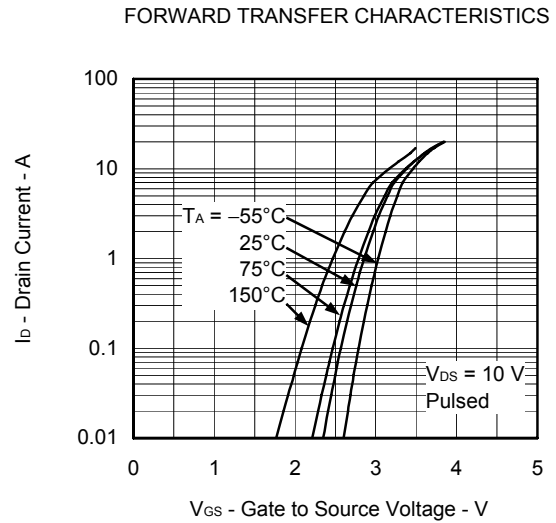
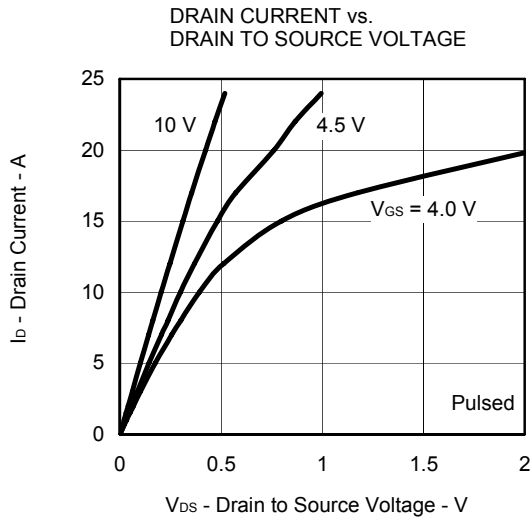
TYPICAL CHARACTERISTICS (T_A = 25°C)

(1) N-channel

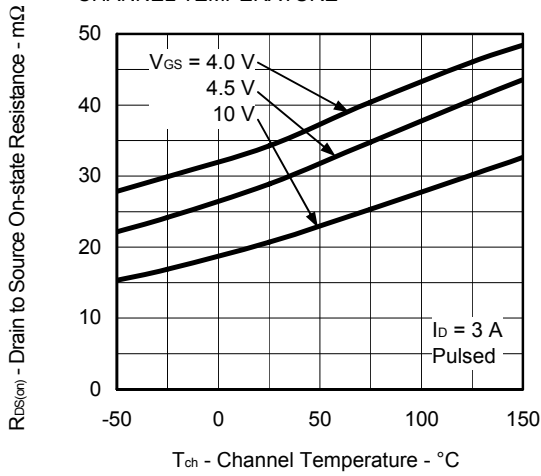


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

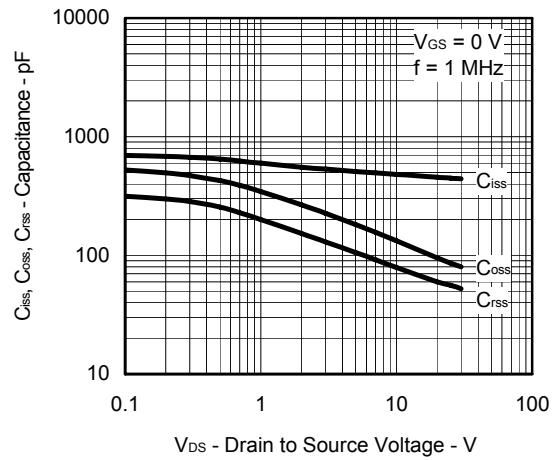




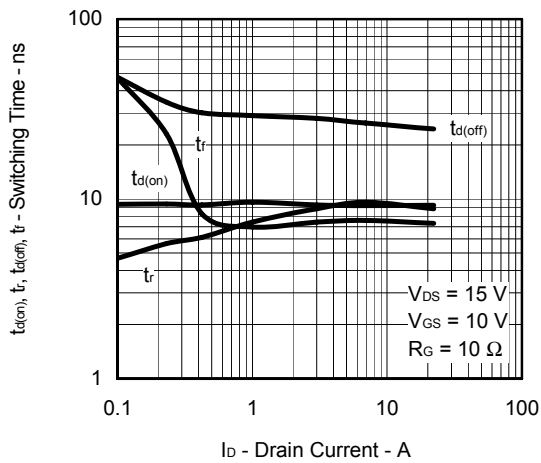
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



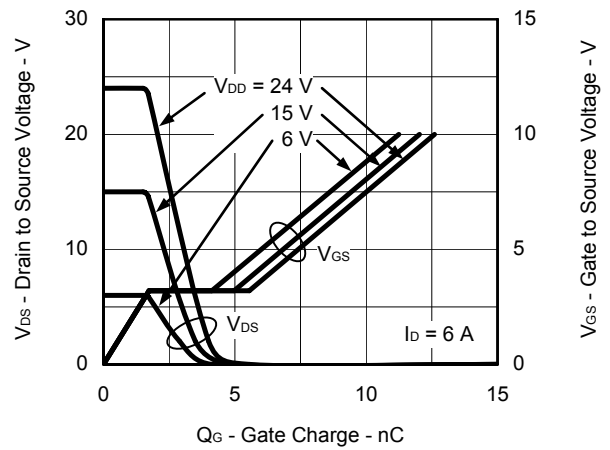
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



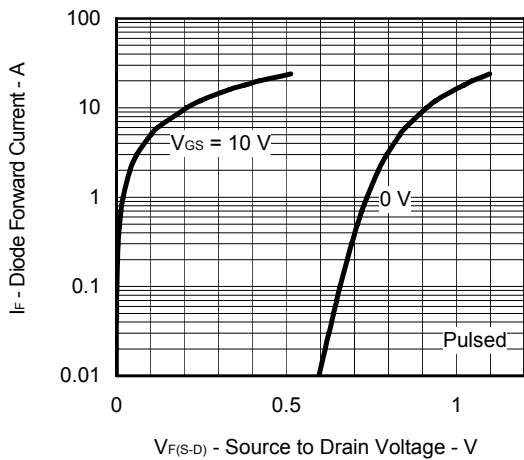
SWITCHING CHARACTERISTICS



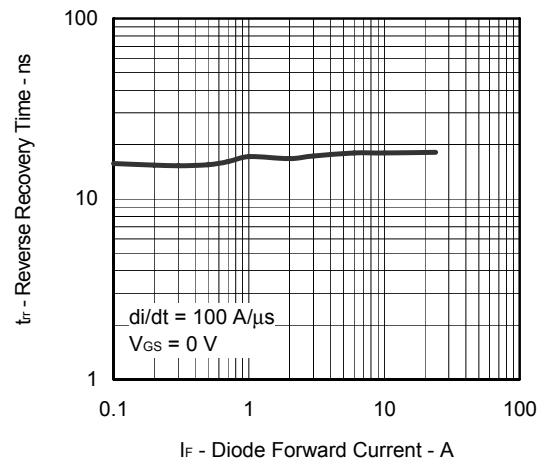
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE

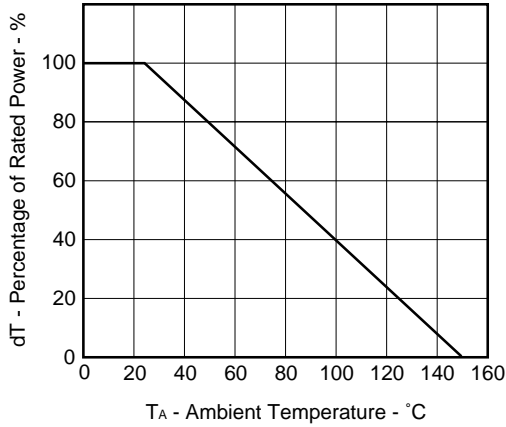


REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT

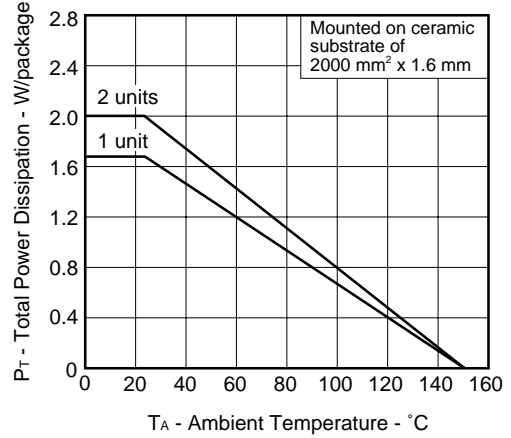


(2) P-channel

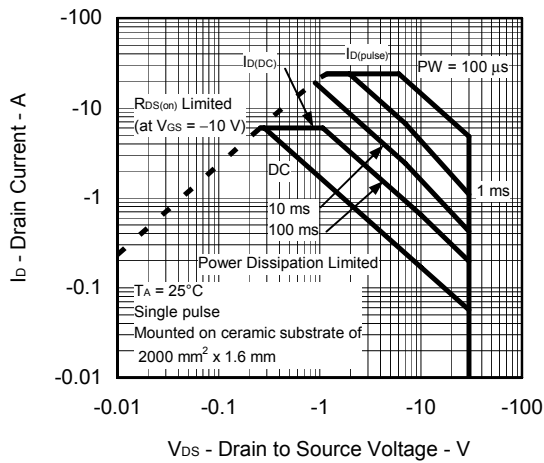
DERATING FACTOR OF FORWARD BIAS SAFE OPERATING AREA



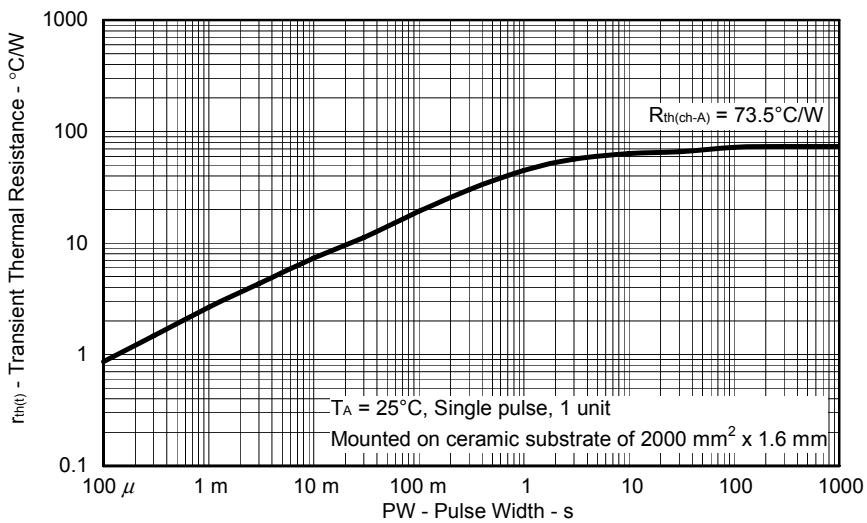
TOTAL POWER DISSIPATION vs. AMBIENT TEMPERATURE

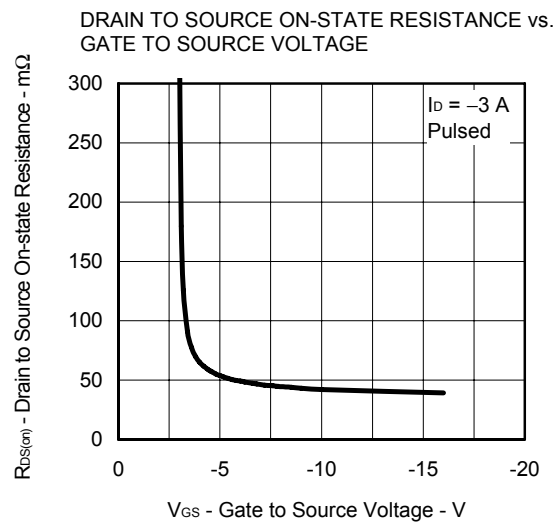
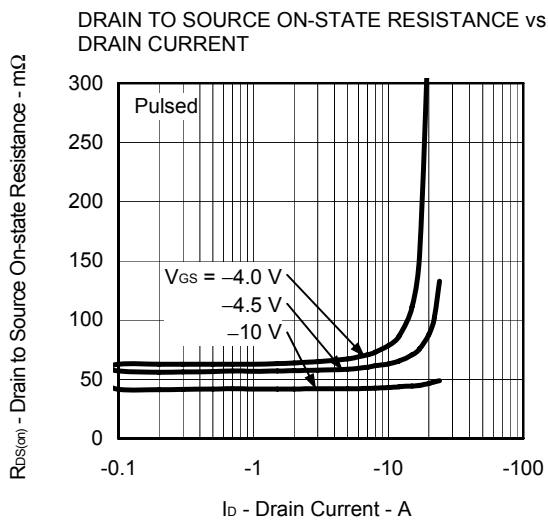
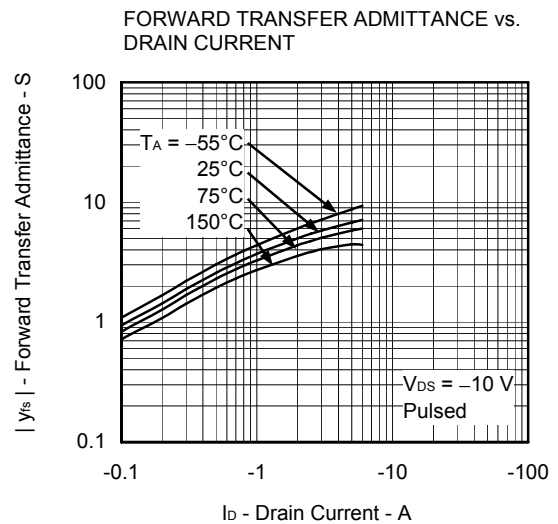
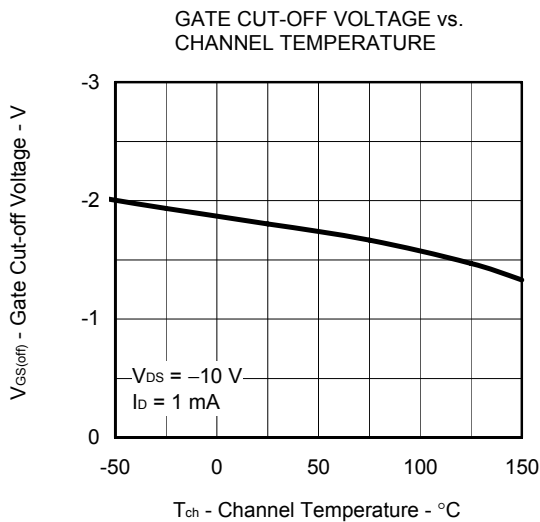
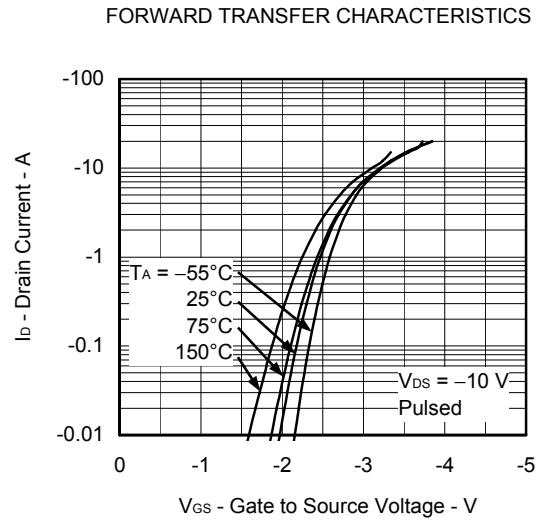
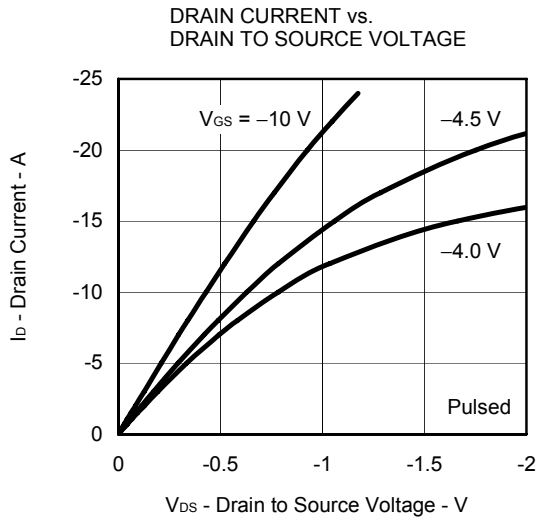


FORWARD BIAS SAFE OPERATING AREA

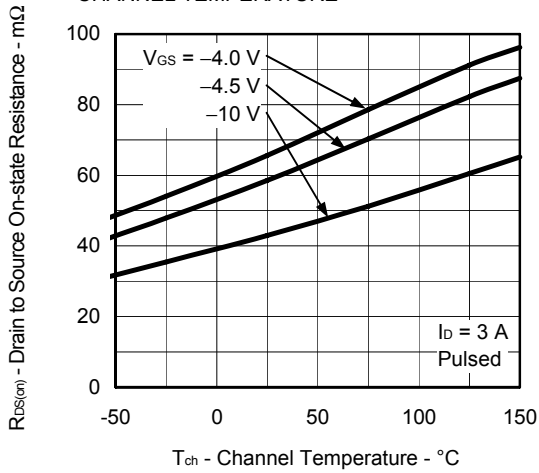


TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

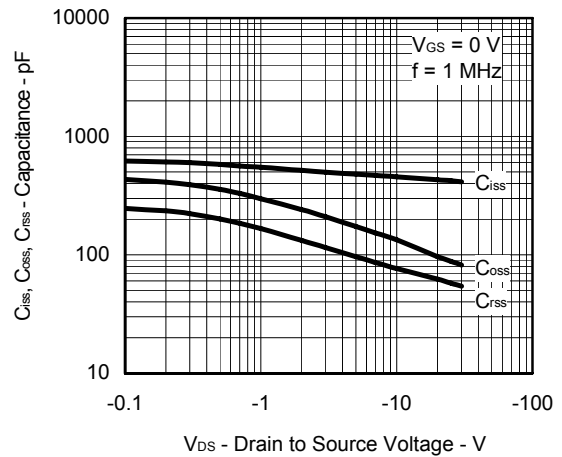




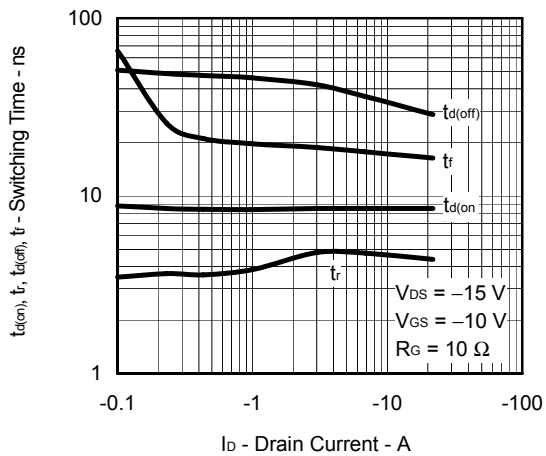
DRAIN TO SOURCE ON-STATE RESISTANCE vs. CHANNEL TEMPERATURE



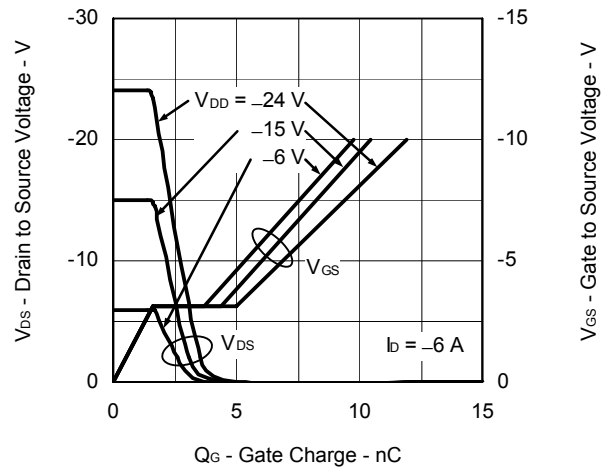
CAPACITANCE vs. DRAIN TO SOURCE VOLTAGE



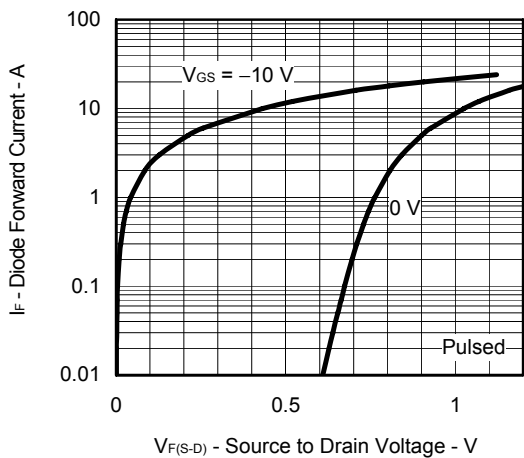
SWITCHING CHARACTERISTICS



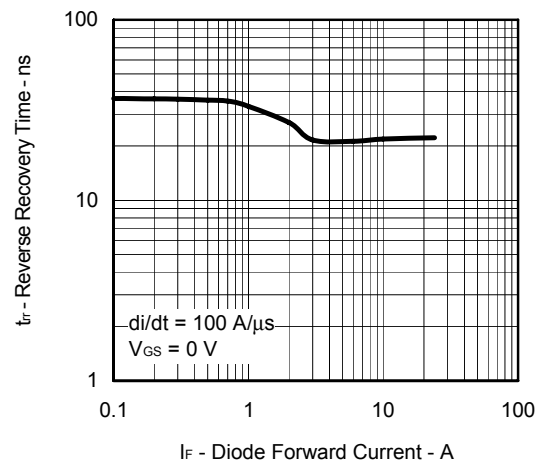
DYNAMIC INPUT/OUTPUT CHARACTERISTICS



SOURCE TO DRAIN DIODE FORWARD VOLTAGE



REVERSE RECOVERY TIME vs. DIODE FORWARD CURRENT



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The "Specific" quality grade applies only to NEC Electronics products developed based on a customer-designated "quality assurance program" for a specific application. The recommended applications of an NEC Electronics product depend on its quality grade, as indicated below. Customers must check the quality grade of each NEC Electronics product before using it in a particular application.

"Standard": Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots.

"Special": Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support).

"Specific": Aircraft, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems and medical equipment for life support, etc.

The quality grade of NEC Electronics products is "Standard" unless otherwise expressly specified in NEC Electronics data sheets or data books, etc. If customers wish to use NEC Electronics products in applications not intended by NEC Electronics, they must contact an NEC Electronics sales representative in advance to determine NEC Electronics' willingness to support a given application.

(Note)

- (1) "NEC Electronics" as used in this statement means NEC Electronics Corporation and also includes its majority-owned subsidiaries.
- (2) "NEC Electronics products" means any product developed or manufactured by or for NEC Electronics (as defined above).